Code No: 131AK

JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD B.Tech I Year I Semester Examinations, May - 2018 **BASIC ELECTRICAL AND ELECTRONICS ENGINEERING** (Common to EEE, ECE, CSE, EIE, IT, ETM)

Time: 3 hours

Note: This question paper contains two parts A and B. Part A is compulsory which carries 25 marks. Answer all questions in Part A. Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions.

PART-A

- 1.a) Define dependent sources. The essential component of a toaster is an electrical element (a resistor) that converts b) electrical energy to heat energy. How much current is drawn by a toaster with resistance 15Ω at 110 V? What is the condition for maximum power transfer in ac circuits? c)
- Derive the expression for resonant frequency. d) e) Define reverse break down voltage of a diode.
- Derive an expression for the average output voltage of a full wave rectifier. f)
- Draw the high frequency model of a transistor. **g**)
- In a BJT, the emitter current is 12 mA and the emitter current is 1.02 times the collector h) current. Find the base current. [3]
- Why FET is called unipolar device? [2] i) [3]
- **i**) What are the special features of FET?
 - **PART-B**

(50 Marks)

- 2.a) Differentiate between active and passive elements.
 - Obtain the equivalent resistance for the circuit in figure 1 and use it to find current *i*. b)

a

[4+6]



R16

Max. Marks: 75

(25 Marks)

[2]

[3]

[2]

[3]

[2]

[3]

[2]

- 3.a) Define impedance, susceptance and admittance with examples.
- b) Using mesh analysis, find I_o in the circuit shown in figure 2. [4+6]



- 4.a) The Q factor of a RLC series circuit is 5 at a resonance frequency of 1 KHz. Assuming the power dissipation of 250W, when the current drawn is 1A, find the circuit parameters.
 - b) Using superposition, find V_o in the circuit shown in figure 3. [5+5]



- 5.a) A 5 μ F condenser is connected in series with a coil having inductance of 50mH. Determine the frequency of resonance, the resistance of the coil if a 50V source causing a current of 10mA is connected. What is the Q factor of the coil?
 - b) Use Norton's theorem to find V_o in the circuit shown in figure 4. [4+6]



Figure: 4

- 6.a) Draw the V I characteristics of a silicon diode, write an expression for diode current and discuss how cut in voltage changes with temperature.
- b) Draw the circuits of a full wave rectifier using 2-diodes and 4-diodes. Discuss the relative merits and demerits. [5+5]

OR

- 7.a) Define diffusion capacitance in a P-N junction diode and discuss its dependence on diode biasing.
 - b) Derive expressions for ripple factor and efficiency of rectification for a full wave rectifier. [5+5]

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- 8.a) Derive expressions for voltage gain, input-resistance and current gain for an emitter follower.
- b) In the Silicon Transistor circuit shown in figure 5, find the maximum base resistance R_B to drive the Transistor into saturation. [5+5]



- 9.a) Discuss the need for biasing a transistor. Briefly explain about self biasing.
- b) Explain how h-parameters can be determined from the static input and output characteristics. [5+5]
- 10.a) Discuss the characteristic differences between a BJT and a FET. Draw a diagram depicting the structure of a N-channel FET and identify the various terminals and the biasing voltages.
 - b) Explain how the pinch off voltage can be modified without changing the physical structure of a JFET. [5+5]

OR

- 11.a) Explain the operation of a FET with a neat diagram and V-I characteristics.
 - b) An N-channel JFET has a pinch voltage of -4.5V and $I_{DSS} = 9mA$ at what value of V_{GS} will I_{DS} equal to 3mA? What is its g_m at this I_{DS} . [5+5]

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